

Vishay General Semiconductor

Dual Trench MOS Barrier Schottky Rectifier

Ultra Low $V_F = 0.49 \text{ V}$ at $I_F = 3 \text{ A}$



DESIGN SUPPORT TOOLS

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PRIMARY CHARACTERISTICS				
I _{F(AV)}	2 x 5 A			
V_{RRM}	80 V			
I _{FSM}	80 A			
V_F at $I_F = 5$ A	0.57 V			
T _J max.	150 °C			
Package	D ² PAK (TO-263AB)			
Circuit configurations	Common cathode			

FEATURES

- Trench MOS Schottky technology
- · Low forward voltage drop, low power losses

• High efficiency operation

RoHS COMPLIANT

FREE

 Meets MSL level 1, per J-STD-020, LF maximum peak of 245 °C

 Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

TYPICAL APPLICATIONS

For use in high frequency converters, switching power supplies, freewheeling diodes, OR-ing diode, DC/DC converters, and reverse battery protection.

MECHANICAL DATA

Case: D²PAK (TO-263AB)

Molding compound meets UL 94 V-0 flammability rating Base P/N-M3 - halogen-free, RoHS-compliant, and commercial grade

Terminals: matte tin plated leads, solderable per

J-STD-002 and JESD 22-B102

M3 suffix meets JESD 201 class 1A whisker test

Polarity: as marked

Mounting Torque: 10 in-lbs maximum

MAXIMUM RATINGS (T _A = 25 °C unless otherwise noted)						
PARAMETER		SYMBOL	VBT1080C	UNIT		
Maximum repetitive peak reverse voltage		V_{RRM}	80	V		
Maximum average forward rectified current (fig. 1)	per device	I _{F(AV)}	10	Α		
	per diode		5			
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load per diode			80	Α		
Voltage rate of change (rated V _R)		dV/dt	10 000	V/µs		
Operating junction and storage temperature range		T_J , T_{STG}	-55 to +150	°C		

ELECTRICAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted)							
PARAMETER	TEST CO	NDITIONS	SYMBOL	TYP.	MAX.	UNIT	
Instantaneous forward voltage per diode (1)	I _F = 3 A	T _A = 25 °C	V _F	0.54	-	V	
	I _F = 5 A			0.63	0.72		
	I _F = 3 A	T _A = 125 °C		0.49	-		
	I _F = 5 A			0.57	0.66		
Reverse current per diode (2)	V 80 V	T _A = 25 °C	- I _R	12	400	μA	
	V _R = 80 V	T _A = 125 °C		6	15	mA	

Notes

(1) Pulse test: 300 µs pulse width, 1 % duty cycle

 $^{(2)}$ Pulse test: Pulse width $\leq 40 \text{ ms}$



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THERMAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted)						
PARAMETER		SYMBOL	VBT1080C	UNIT		
Typical thermal resistance	per diode	$R_{ hetaJC}$	3.5	°C/W		
	per device		2.5			

ORDERING INFORMATION (Example)							
PACKAGE	PREFERRED P/N	UNIT WEIGHT (g)	PACKAGE CODE	BASE QUANTITY	DELIVERY MODE		
TO-263AB	VBT1080C-M3/4W	1.35	4W	50/tube	Tube		
TO-263AB	VBT1080C-M3/8W	1.35	8W	800/reel	Tape and reel		

RATINGS AND CHARACTERISTICS CURVES (T_A = 25 °C unless otherwise noted)

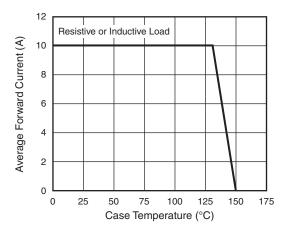


Fig. 1 - Maximum Forward Current Derating Curve

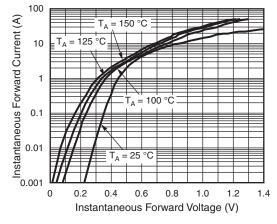


Fig. 3 - Typical Instantaneous Forward Characteristics Per Diode

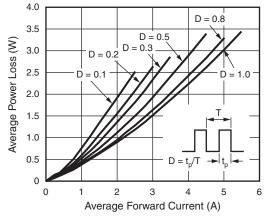


Fig. 2 - Forward Power Loss Characteristics Per Diode

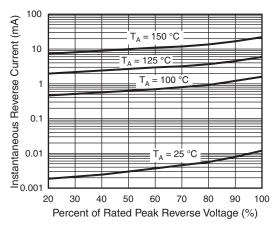


Fig. 4 - Typical Reverse Characteristics Per Diode



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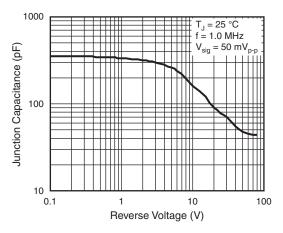


Fig. 5 - Typical Junction Capacitance Per Diode

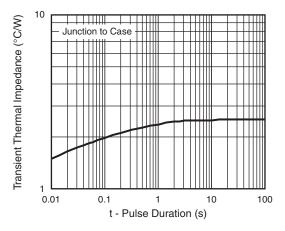
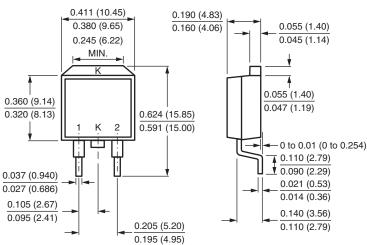


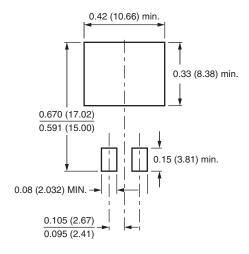
Fig. 6 - Typical Transient Thermal Impedance Per Diode

PACKAGE OUTLINE DIMENSIONS in inches (millimeters)

D²PAK (TO-263AB)



Mounting Pad Layout





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